



650V N-Channel MOSFET

650 V Voltage

Current

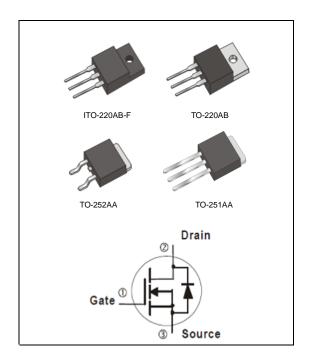
7 A

Features

- Super-Junction Technology
- $R_{DS(ON)}$, $V_{GS}@10V$, $I_D@2.0A<0.66\Omega$
- High switching speed
- Low Gate Charge
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std.
- (Halogen Free)

Mechanical Data

- Case: TO-251AA, ,TO-252AA ,TO-220AB, ITO-220AB-F Package
- Terminals: Solderable per MIL-STD-750, Method 2026



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	TO-251AA	TO-220AB	ITO-220AB-F	TO-252AA	UNITS
Drain-Source Voltage		V_{DS}	650				
Gate-Source Voltage		V_{GS}	<u>+</u> 30				V
Continuous Drain Current		I _D	7				Α
Pulsed Drain Current		I _{DM}	28				Α
Single Pulse Avalanche Energy (Note 1)		E _{AS}	100				mJ
Power Dissipation	T _C =25°C	P _D	62	62	27	62	W
	Derate above 25°C		0.5	0.5	0.22	0.5	W/°C
Operating Junction and		T_J , T_{STG}	-55~150				
Storage Temperature Range							
Typical Thermal Resistance							
- Junction to Case		$R_{ heta JC}$	2.0	2.0	4.63	2.0	°C/W
- Junction to Ambient		$R_{ heta JA}$	110	62.5	120	110	

• Limited only By Maximum Junction Temperature





Electrical Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static			•			
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS}=0V,I_{D}=250uA$	650	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=250$ uA	2	3	4	V
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V,I _D =2.0A	-	0.58	0.66	Ω
Zero Gate Voltage Drain Current	I_{DSS}	V _{DS} =650V,V _{GS} =0V	-	-	1.0	uA
Gate-Source Leakage Current	I_{GSS}	$V_{GS}=\underline{+}30V, V_{DS}=0V$	-	-	<u>+</u> 100	nA
Diode Forward Voltage	V_{SD}	I _S =1A,V _{GS} =0V	-	0.8	1.4	V
Dynamic ^(Note 4)						
Total Gate Charge	Q_g	V 500V I 7.0A	-	14	-	nC
Gate-Source Charge	Q_gs	V_{DS} =520V, I_{D} =7.0A, V_{GS} =10V (Note 2,3)	-	3.7	-	
Gate-Drain Charge	Q_gd	V _{GS} =10V	-	5.4	-	
Input Capacitance	Ciss	\/ 400\/ \/ 0\/	-	577	-	pF
Output Capacitance	Coss	$V_{DS}=100V, V_{GS}=0V,$	-	25	-	
Reverse Transfer Capacitance	Crss	f=1.0MHZ	-	27	-	
Turn-On Delay Time	td _(on)	td _(on)		13	-	
Turn-On Rise Time	t _r	V _{DD} =325V, I _D =7.0A,	-	27	-	n
Turn-Off Delay Time	td _(off)	$V_{GS}=10V, R_{G}=25\Omega$		35	-	ns
Turn-Off Fall Time	t _f	(-	22	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	Is		-	-	7	А
Maximum Pulsed Drain-Source Diode Forward Current	I _{SM}		-	-	28	А

NOTES:

- 1. L=50mH, I_{AS} =2A, V_{DD} =50V, R_{G} =25 ohm, Starting T_{J} =25 $^{\circ}$ C
- 2. Pulse width < 300us, Duty cycle < 2%
- 3. Essentially independent of operating temperature typical characteristics.
- 4. Guaranteed by design, not subject to production testing





TYPICAL CHARACTERISTIC CURVES

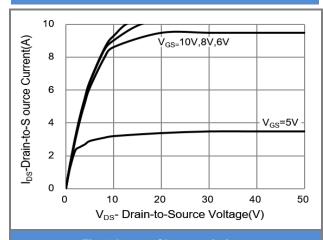


Fig.1 Output Characteristics

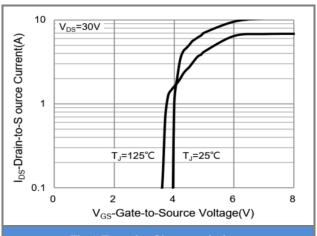


Fig.2 Transfer Characteristics

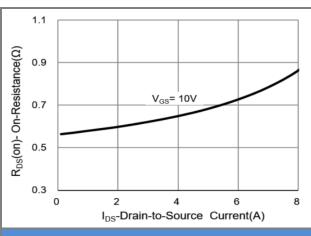


Fig.3 On-Resistance vs. Drain Current

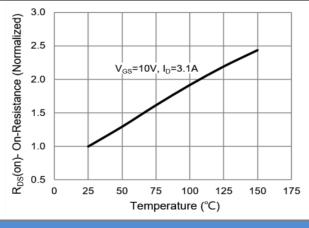


Fig.4 Resistance vs. Junction Temperature

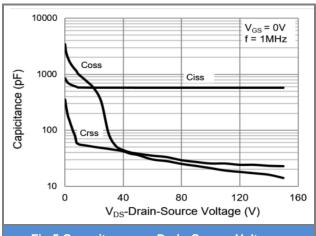


Fig.5 Capacitance vs. Drain-Source Voltage

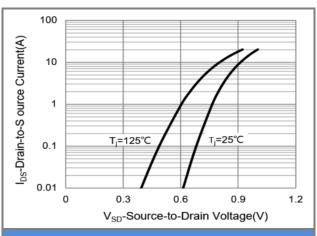


Fig.6 Source-Drain Diode Forward Voltage





TYPICAL CHARACTERISTIC CURVES

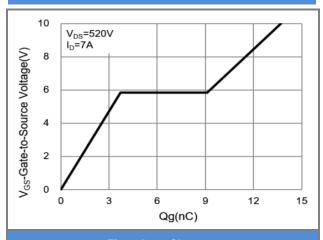


Fig.7 Gate Charge

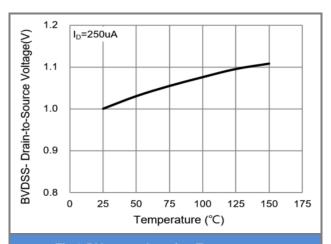


Fig.8 BV_{DSS} vs. Junction Temperature

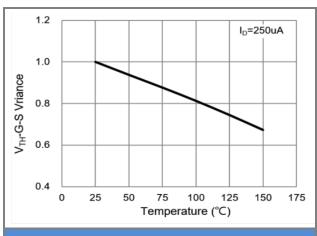


Fig.9 Threshold Voltage Variation with Temperature

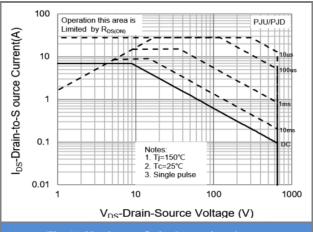


Fig.10 Maximum Safe Operating Area

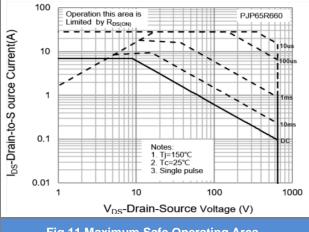


Fig.11 Maximum Safe Operating Area

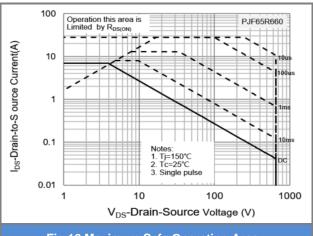


Fig.12 Maximum Safe Operating Area



0.00001



10

PJU65R660 / PJD65R660 / PJP65R660 / PJF65R660

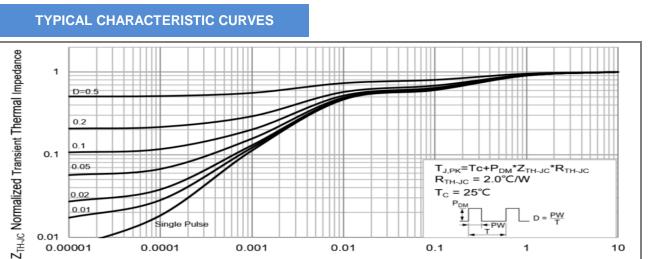


Fig.13 PJU/PJD Normalized Transient Thermal Impedance vs. Pulse Width

t, Pulse Width

0.01

0.1

0.001

0.0001

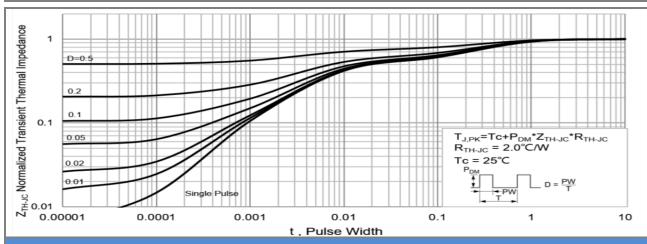


Fig.14 PJP65R660 Normalized Transient Thermal Impedance vs. Pulse Width

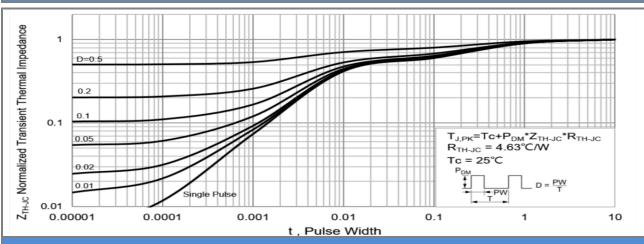
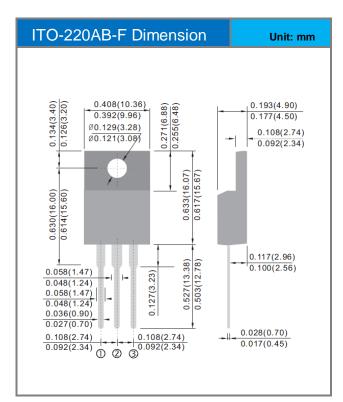


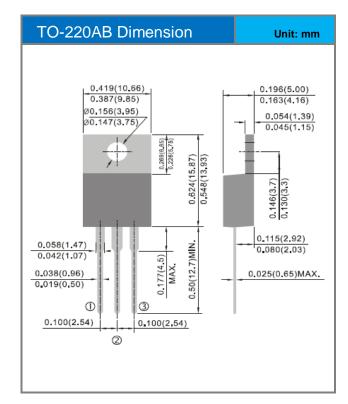
Fig.15 PJF65R660 Normalized Transient Thermal Impedance vs. Pulse Width

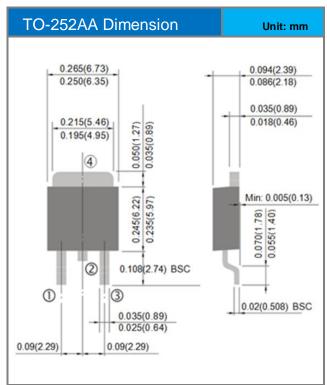


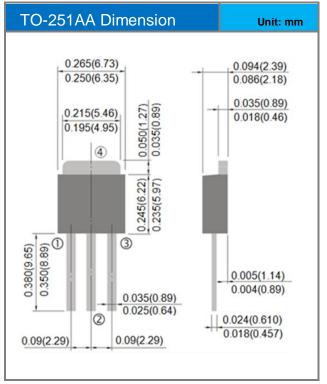


Packaging Information













PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJU65R660_T0_00001	TO-251AA	80pcs / Tube	U65R660	Halogen free
PJD65R660_L2_00001	TO-252AA	3,000pcs / 13" reel	D65R660	Halogen free
PJP65R660_T0_00001	TO-220AB	50pcs / Tube	P65R660	Halogen free
PJF65R660_T0_00001	ITO-220AB-F	50pcs / Tube	F65R660	Halogen free





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